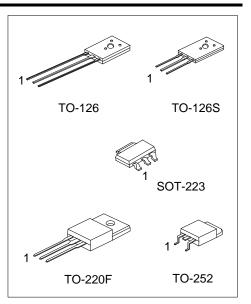
REVERSE BLOCKING TRIODE THYRISTORS

DESCRIPTION

PNPN devices designed for high volume consumer applications such as temperature, light and speed control; process and remote control, and warning systems where reliability of operation is important.

■ FEATURES

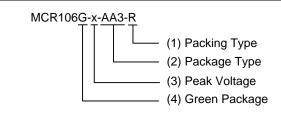
- * Glass-passivated surface for reliability and uniformity
- * Power rated at economical prices
- * Practical level triggering and holding characteristics
- * Flat, rugged, thermopad construction for low thermal resistance, high heat dissipation and durability



■ ORDERING INFORMATION

Ordering Number		Dooleage	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MCR106L-x-AA3-R	MCR106G-x-AA3-R	SOT-223	K	Α	G	Tape Reel	
MCR106L-x-TF3-T	MCR106G-x-TF3-T	TO-220F	K	Α	G	Tube	
MCR106L-x-TN3-R	MCR106G-x-TN3-R	TO-252	K	Α	G	Tape Reel	
MCR106L-x-T60-K	MCR106G-x-T60-K	TO-126	K	Α	G	Bulk	
MCR106L-x-T6S-K	MCR106G-x-T6S-K	TO-126S	K	Α	G	Bulk	

Note: Pin assignment: K: Cathode A: Anode G: Gate



- (1) T: Tube, K: Bulk, R: Tape Reel
- (2) AA3: SOT-223, TF3: TO-220F, , TN3: TO-252,

T60: TO-126, T6S: TO-126S

(3) 6: 400V, 8: 600V

(4) G: Halogen Free and Lead Free, L: Lead Free

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■ MARKING

PACKAGE	MARKING
SOT-223	MCR106 ☐ L: Lead Free → G: Halogen Free → Date Code
TO-252 TO-252D	UTC MCR106 G: Halogen Free Lot Code 1
TO-126 TO-126S	Date Code MCR106

■ **ABSOLUTE MAXIMUM RATINGS** (T_J=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT	
Peak Repetitive Forward and Reverse Blocking	MCR106-6	\/ \/	400	V
Voltage (Note 1) (T _J =110°C, R _{GK} =1kΩ)	MCR106-8	V_{DRM}, V_{RRM}	600	V
RMS Forward Current (All conduction Angles)		I _{T(RMS)}	4	Α
Average Forward Current (T _C =93°C or T _A =30°C)		I _{T(AV)}	2.55	Α
Peak Non-repetitive Surge Current			25	Α
(1/2 Cycle, 60Hz, T _J =-40 ~ +110°C)		I _{TSM}	25	Α
Circuit Fusing Considerations (t=8.3 ms)		l ² t	2.6	A^2S
Peak Gate Power		P_{GM}	0.5	W
Average Gate Power		P _{G(AV)}	0.1	W
Peak Forward Gate Current		I _{GM}	0.2	Α
Peak Reversed Gate Voltage		V_{RGM}	6	V
Mounting Torque (Note 2)			6	In. lb.
Junction Temperature		T_J	+110	°C
Storage Temperature	·	T _{STG}	-40 ~ +150	°C

- Notes: 1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage of the devices are exceeded.
 - 2. Torque rating applies with use of compression washer (B52200-F006 or equivalent). Mounting torque in excess of 6 in. lb. does not appreciably lower case-to-sink thermal resistance. Anode lead and heatsink contact pad are common. For soldering purposes (either terminal connection or device mounting), soldering temperatures shall not exceed +200°C. For optimum results, an activated flux (oxide removing) is recommended.
 - 3. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

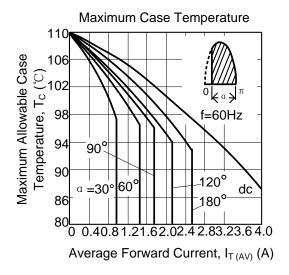
PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223		180	°C/W
	TO-220F/TO-252	θ_{JA}	62.5	°C/W
	TO-126/TO-126S	TO-126/TO-126S		°C/W
TO-126/TO-126S SOT-223 TO-220F TO-126/TO-126S ΘJC TO-252	SOT-223		18.3	°C/W
		3.31	°C/W	
	TO-126/TO-126S	AlC	3	°C/W
	TO-252		2.6	°C/W

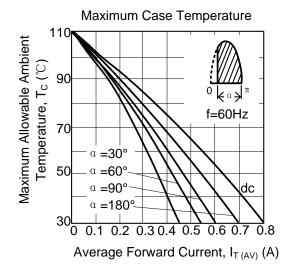
■ ELECTRICAL CHARACTERISTICS (T_C=25°C and R_{GK}=1000Ω, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Peak Forward or Reverse Blocking		T _J =25°C			10	μΑ
Current (V _{AK} =Rated V _{DRM} or V _{RRM})	IDRM, IRRM	T _J =100°C			200	μΑ
Forward "On" Voltage (I _{TM} =4A peak)	V_{TM}		•		2	V
Gate Trigger Current (continuous DC)		V_{AK} =7 V , R_L =100 Ω			200	
(Note)	I _{GT}	V_{AK} =7 V , R_L =100 Ω , T_C =-40 $^{\circ}$ C			500	μΑ
Gate Trigger Voltage (continuous DC)	V_{GT}	V_{AK} =7 V , R_L =100 Ω , T_C =25 $^{\circ}$ C			1	V
Gate Non-Trigger Voltage	V_{GD}	V_{AK} =Rated V_{DRM} , R_L =100 Ω , T_J =110 $^{\circ}$ C	0.2			V
Holding Current	I _H	V _{AK} =7V, T _C =25°C			5	mΑ
Forward Voltage Application Rate	dv/dt	T _J =110°C		10		V/μs

Note: R_{GK} current is not included in measurement.

■ TYPICAL CHARACTERISTICS





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